

DIO3166

Low On-Resistance, Low THD Analog Switch

Features

- 5.5 tolerant on control pin
- Voltage Operation: 1.65V to 5.5V
- Low On Resistance: 1Ω@ 4.2V V_{cc}
- Excellent On Resistance Matching
- Low Total Harmonic Distortion (THD)
- Low Charge Injection
- Low power consumption
- Green or RoHS Packaged:
SC70-5, SOT23-5
- 1.5kV CDM ESD Rating,
8kV HBM ESD

Descriptions

The DIO3166 is a low power, single pole double throw analog switch, which is designed to operate from a single 1.65V to 5.5V supply.

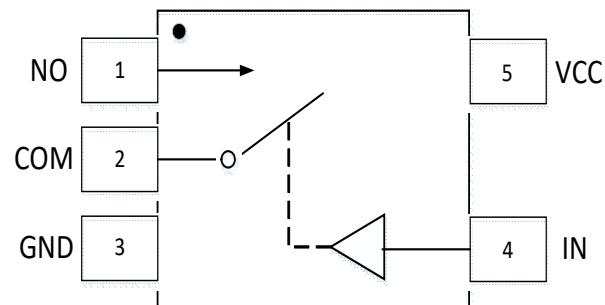
DIO3166 has low on resistance, excellent on resistance matching and very low total harmonic distortion performance to prevent signal distortion during signals transferring. All these features make DIO3166 suitable for portable audio applications.

DIO3166 is available in two type package: SC70-5, SOT23-5.

Applications

- Cell Phones
- PDAs and MP3s
- Portable Instrumentation
- Battery Powered Communications
- Computer Peripherals

Block Diagram



Ordering Information

Order Part Number	Top Marking		T _A	Package	
DIO3166SC5	W316	Green or RoHS	-40 to +85 °C	SC70-5	Tape & Reel, 3000
DIO3166ST5	W316	Green or RoHS	-40 to +85 °C	SOT23-5	Tape & Reel, 3000

Pin Assignment

SOT23-5/SC70-5

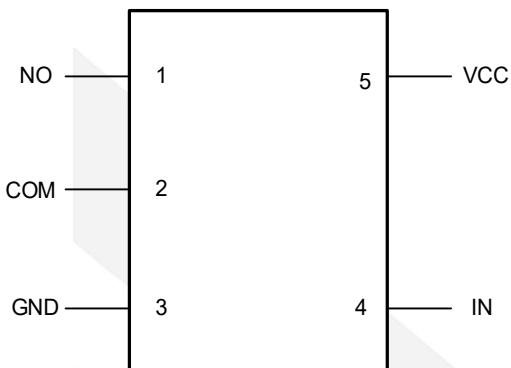


Figure 1 Top View

Pin Descriptions

Pin Name	Description
NO	Normally open
GND	Ground
COM	Common
VCC	Power supply
IN	Control

Truth Table

IN	COM to NO
L	OFF
H	ON



DIO3166

Absolute Maximum Ratings

Stresses beyond those listed under "Absolute Maximum Rating" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other condition beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Parameter	Min.	Max.	Unit
Supply Voltage(V _{cc})	-0.5	6.5	V
DC Switch Voltage(V _{sw})	-0.5	V _{cc} +0.5	V
DC Control Voltage(V _{IN})	-0.5	6.5	V
On-state Switch Current (I _{sw})	-200	200	mA
On-state peak Switch Current (I _{sw})	-400	400	
Continuous current through GND	-100	100	mA
Storage Temperature Range (T _{STG})	-65	150	°C
SC70-5 Package (θ _{JA})		259	°C/W
SOT23-5 Package (θ _{JA})		165	
ESD	HBM, JEDEC:JESD22-A114	8	kV
	CDM, JEDEC: JESD22-C101	1.5	

Recommend Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation to ensure optimal performance to the datasheet specifications. DIOO does not recommend exceeding them or designing to Absolute Maximum Ratings.

Parameter	Min.	Max.	Unit
Supply Voltage (V _{cc})	1.65	5.5	V
Control Input Voltage (V _{IN})	0	5.5	V
Switch Input Voltage (V _{sw} , V _{com})	0	V _{cc}	V
Operating Temperature (T _A)	-40	85	°C



DIO3166

Electrical Characteristics

All typical value are at $V_{CC}=4.2V$; $T_A = 25^\circ C$, unless otherwise specified.

Symbol	Parameter	Conditions	Temp.	Min	Typ	Max	Unit	
V_{IH}	Input voltage high		-40 to 85°C	2.4			V	
V_{IL}	Input voltage low		-40 to 85°C			0.8	V	
I_{IN}	Control input leakage	$V_{IN}=4.2V$ or 0V, $V_{CC}=4.2V$	25°C	-2		2	nA	
			-40 to 85°C	-100		100		
$I_{NO(OFF)}$	NO, COM off leakage current See Figure 3	$V_{SW}=0.3V, 3.3V$, $V_{COM}=3.3V, 0.3V, V_{CC}=4.2V$	25°C	-20	2	20	nA	
			-40 to 85°C	-100		100		
$I_{NO(PWOFF)}$ $I_{COM(PWOFF)}$		$V_{SW}=0V$ to 4.2V, $V_{COM}=4.2V$ to 0V; $V_{CC}=0V$	25°C	-1	0.2	1	μA	
			-40 to 85°C	-20		20		
$I_{COM(ON)}$	COM on leakage current	$V_{COM}=0.3V, 3.3V, V_{SW}=0.3V, 3.3V$, or floating, $V_{CC}=4.2V$	25°C	-20	2	20	nA	
			-40 to 85°C	-100		100		
I_{CC}	Quiescent supply current	$V_{CC}=4.2V$, $V_{IN}=V_{CC}$ or GND, Switch ON or OFF	25°C		10	50	nA	
			-40 to 85°C			500		
R_{ON}	Switch on Resistance See Figure 2	$V_{CC}=4.2V$, $V_{SW}=1V$, $I_{SW}=-100mA$	25°C		1	1.5	Ω	
			-40 to 85°C			2.0		
ΔR_{ON}	On Resistance Matching between Channels	$V_{CC}=4.2V$, $V_{SW}=1V$, $I_{SW}=-100mA$	25°C		0.05	0.2	Ω	
			-40 to 85°C			0.3		
$R_{FLT(ON)}$	On Resistance Flatness	$V_{CC}=4.2V$, $V_{SWC}=1V, 3.5V$, $I_{SW}=-100mA$	-40 to 85°C		0.8	1.2	Ω	
T_{ON}	Turn-On Time See Figure 6	$V_{SW}=1.5V$ or 0V, $R_L = 50\Omega$, $C_L = 35pF$, See Figure 6	25°C		12	35	ns	
T_{OFF}	Turn-Off Time See Figure 6	$V_{SW}=1.5V$ or 0V, $R_L = 50\Omega$, $C_L = 35pF$, See Figure 6	25°C		5	30	ns	
T_{BBM}	Break before make time	$V_{SW}=V_{CC}, R_L = 50\Omega$, $C_L = 35pF$	25°C		6	20	ns	
OIRR	Off Isolation	$R_L = 50\Omega$, Signal=0dBm, f=1MHz	25°C		-70		dB	
BW	-3dB bandwidth See Figure 5	$R_L = 50\Omega$, Signal=0dBm, See Figure 5	25°C		100		MHz	
THD	Total harmonic distortion	$R_L = 600\Omega$, $C_L=50pF$, f=20Hz to 20kHz, See Figure 5	25°C		0.004		%	
C_{IN}	Control Pin input Capacitance	$V_{IN}=V_{CC}$ or 0V	25°C		1.5		pF	
C_{OFF}	OFF Capacitance See Figure 4	Switch Off, $V_{SW}=V_{CC}$ or 0V See Figure 4	25°C		22		pF	
C_{ON}	On Capacitance See Figure 4	Switch On, $V_{COM}=V_{CC}$ or 0V See Figure 4	25°C		49		pF	

Low On-Resistance, Low THD Analog Switch



DIO3166

Electrical Characteristics

All typical value are at $V_{CC}=2.7V$ to $3.6V$; $T_A = 25^\circ C$, unless otherwise specified.

Symbol	Parameter	Conditions	Temp.	Min	Typ	Max.	Unit	
V_{IH}	Input voltage high		-40 to $85^\circ C$	2.4			V	
V_{IL}	Input voltage low		-40 to $85^\circ C$			0.8	V	
I_{IN}	Control input leakage	$V_{IN}=2.7V$ or 0V, $V_{CC}=2.7V$	25°C	-2		2	nA	
			-40 to $85^\circ C$	-100		100		
			25°C	-20	2	20		
$I_{NO(OFF)}$	NO, COM off leakage current See Figure 3	$V_{SW}=0.3V$, $3.3V$; $V_{COM}=3.3$ to $0.3V$ $V_{CC}=3.6V$	-40 to $85^\circ C$	-50		50	nA	
			25°C	-1	0.2	1		
$I_{NO(PWOFF)}$ $I_{COM(PWOFF)}$		$V_{SW}=0V$ to $3.3V$, $V_{COM}=3.3V$ to $0V$; $V_{CC}=0V$	-40 to $85^\circ C$	-15		15	μA	
			25°C	-10	2	10		
$I_{COM(ON)}$	COM on leakage current	$V_{COM}=0.3V$, $3.3V$, $V_{SW}=0.3V$, $3.3V$, or floating, $V_{CC}=3.6V$	25°C	-20		20	nA	
			-40 to $85^\circ C$					
I_{CC}	Quiescent supply current	$V_{CC}=3.6V$, $V_{IN}=V_{CC}$ or GND, Switch ON or OFF	25°C		10	25	nA	
			-40 to $85^\circ C$			100		
R_{ON}	Switch on Resistance See Figure 2	$V_{CC}=2.7V$, $V_{SW}=1.0V$, $I_{SW}=-100mA$	25°C		1.5	2.2	Ω	
			-40 to $85^\circ C$			2.6		
ΔR_{ON}	On Resistance Matching between Channels	$V_{CC}=2.7V$, $V_{SW}=1.0V$, $I_{SW}=-100mA$	25°C		0.1	0.3	Ω	
			-40 to $85^\circ C$			0.5		
$R_{FLT(ON)}$	On Resistance Flatness	$V_{CC}=2.7V$, $V_{SW}=1V$, $2V$, $I_{SW}=-100mA$	-40 to $85^\circ C$		0.9	1.5	Ω	
T_{ON}	Turn-On Time See Figure 6	$V_{SW}=1.5V$ or $0V$, $R_L = 50\Omega$, $C_L = 35pF$ See Figure 6	25°C		16	35	ns	
T_{OFF}	Turn-Off Time See Figure 6	$V_{SW}=1.5V$ or $0V$, $R_L = 50\Omega$, $C_L = 35pF$ See Figure 6	25°C		9	30	ns	
T_{BBM}	Break before make time	$V_{SW}=V_{CC}$, $R_L = 50\Omega$, $C_L = 35pF$	25°C		9	40	ns	
OIRR	Off Isolation	$R_L = 50\Omega$, Signal=0dBm, $f=1MHz$	25°C		-70		dB	
BW	-3dB bandwidth See Figure 5	$R_L = 50\Omega$, Signal=0dBm, See Figure 5	25°C		100		MHz	
THD	Total harmonic distortion	$R_L = 600\Omega$, $C_L=50pF$, $f=20Hz$ to $20kHz$ See Figure 5	25°C		0.01		%	
C_{IN}	Control Pin input Capacitance	$V_{IN}=V_{CC}$ or $0V$	25°C		1.5		pF	
C_{OFF}	OFF Capacitance See Figure 4	Switch Off, $V_{SW}=V_{CC}$ or $0V$ See Figure 4	25°C		22		pF	
C_{ON}	On Capacitance See Figure 4	Switch On, $V_{COM}=V_{CC}$ or $0V$ See Figure 4	25°C		49		pF	

Low On-Resistance, Low THD Analog Switch

Test Diagrams

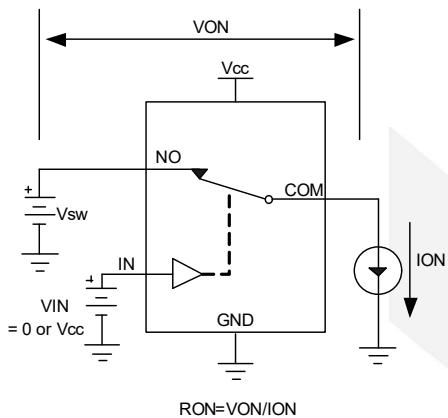


Figure 2 Switch on resistor

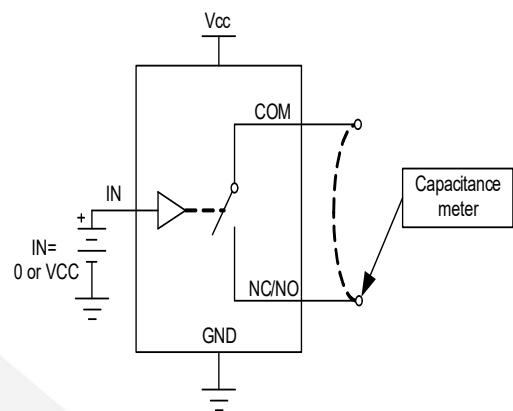


Figure 3 On/off Capacitance test

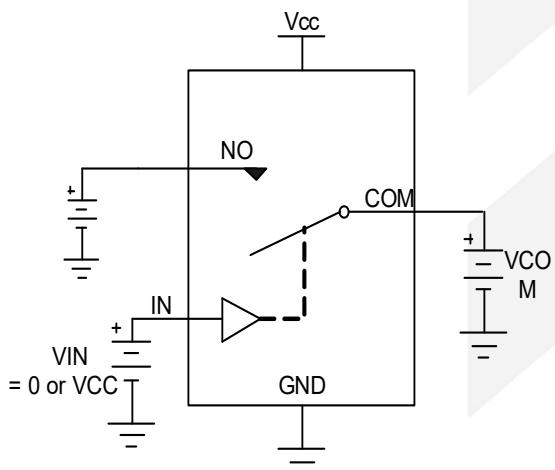


Figure 4 Switch Off Leakage

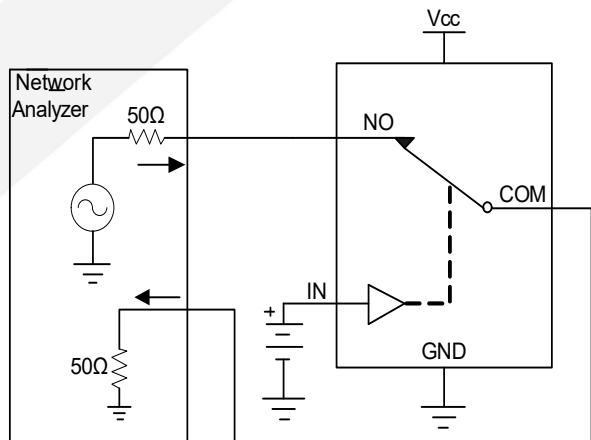


Figure 5 Bandwidth

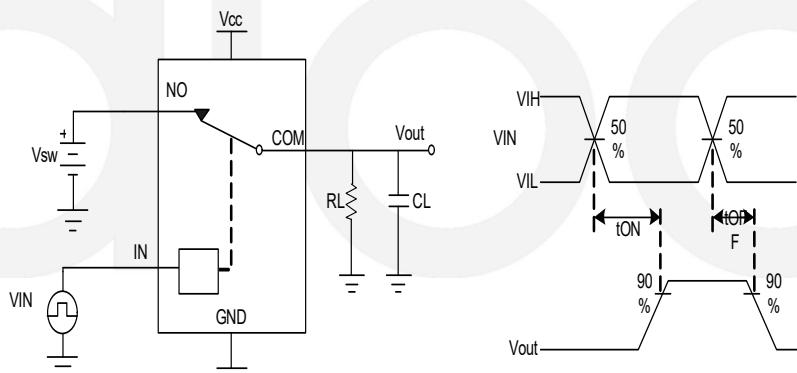


Figure 6 Turn-On/Turn-Off



DIO3166

Low On-Resistance, Low THD Analog Switch

CONTACT US

Dioo is a professional design and sales corporation for high-quality and performance analog semiconductors. The company focuses on industry markets, such as, cell phone, handheld products, laptop, and medical equipment and so on. Dioo's product families include analog signal processing and amplifying, LED drivers and charger IC. Go to <http://www.dioo.com> for a complete list of Dioo product families.

For additional product information, or full datasheet, please contact with our Sales Department or Representatives.